



STEALTHTM II Rectifier

The FFPF08S60ST is STEALTH[™] II rectifier with soft recovery characteristics. It is silicon nitride passivated ion-implanted epi-

This device is intended for use as freewheeling of boost diode in switching power supplies and other power swithching applica-

tions. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits

8A, 600V STEALTH[™] II Rectifier

reducing power loss in the switching transistors.

taxial planar construction.

FFPF08S60ST

Features

- + High Speed Switching, t_{rr} < 30ns @ I_F = 8A
- High Reverse Voltage and High Reliability
- RoHS component

Applications

- General Purpose
- Switching Mode Power Supply
- · Boost Diode in continuous mode power factor corrections
- · Power switching circuits



Pin Assignments





1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{RRM}	Peak Repetitive Reverse Voltage	600	V
V _{RWM}	Working Peak Reverse Voltage	600	V
V _R	DC Blocking Voltage	600	V
I _{F(AV)}	Average Rectified Forward Current @ $T_C = 95 ^{\circ}C$	8	А
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	80	А
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C

Thermal Characteristics

Symbol	Parameter	Мах	Units
$R_{ ext{ heta}JC}$	Maximum Thermal Resistance, Junction to Case	3.4	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F08S60ST	FFPF08S60STTU	TO-220F-2L	-	-	50

Parameter Conditions		Min.	Тур.	Мах	Units	
V _{FM} ¹	I _F = 8A I _F = 8A	T _C = 25 °C T _C = 125 °C	-	2.1 1.6	2.6	V V
I _{RM} ¹	V _R = 600V V _R = 600V	T _C = 25 °C T _C = 125 °C	-	-	100 500	μΑ μΑ
t _{rr}	I _F =1A, di/dt = 100A/µs, V _R = 30V	T _C = 25 °C	-	-	25	ns
trr Irr S factor Q _{rr}	I _F =8A, di/dt = 200A/μs, V _R = 390V	T _C = 25 °C	- - -	19 2.2 0.6 21	30 - - -	ns A nC
trr Irr S factor Q _{rr}	I _F =8A, di/dt = 200A/μs, V _R = 390V	T _C = 125 °C	- - -	58 4.3 1.3 125		ns A nC
W _{AVL}	Avalanche Energy (L = 40mH)	•	20	-	-	mJ

Electrical Characteristics T_C = 25°C unless otherwise noted

Notes:

1. Pulse : Test Pulse width = 300μ s, Duty Cycle = 2%

Test Circuit and Waveforms



Typical Performance Characteristics T_C = 25°C unless otherwise noted

Figure 1. Typical Forward Voltage Drop

Figure 2. Typical Reverse Current







Figure 5. Typical Reverse Recovery Current





Figure 4. Typical Reverse Recovery Time



Figure 6. Forward Current Deration Curve



FFPF08S60ST





SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

2Cool™	F-PFS™	PowerTrench®	The Power Franchise [®]
AccuPower™	FRFET®	PowerXS™	the . ®
AX-CAP™*	Global Power Resource SM	Programmable Active Droop™	puwer
BitSiC [®]	Green Bridge™	QFET®	franchise TinyBoost™
Build it Now™	Green FPS™	QS™	
CorePLUS™	Green FPS™ e-Series™	Quiet Series™	TinyBuck™
CorePOWER™	Gmax™	RapidConfigure™	TinyCalc™
CROSSVOLT™	GTO™		TinyLogic [®]
CTL™	IntelliMAX™		TINYOPTO™
Current Transfer Logic™	ISOPLANAR™	Saving our world, 1mW/W/kW at a time™	TinyPower™
DEUXPEED®	Marking Small Speakers Sound Loude		TinyPWM™
Dual Cool™	and Better™	SmartMax™	TinyWire™
EcoSPARK [®]	MegaBuck™	SMART START™	TranSiC [®]
EfficentMax™	MICROCOUPLER™	Solutions for Your Success™	TriFault Detect™
ESBC™	MicroFET™	SPM [®]	TRUECURRENT [®] *
2000	MicroPak™	STEALTH™	µSerDes™
L [®]	MicroPak2™	SuperFET®	\mathcal{M}
	MillerDrive™	SuperSOT™-3	∕ Ser <mark>Des</mark> ™
Fairchild®	MotionMax™	SuperSOT™-6	UHC [®]
Fairchild Semiconductor®	Motion-SPM™	SuperSOT™-8	Ultra FRFET™
FACT Quiet Series™	mWSaver™	SupreMOS [®]	UniFET™
FACT®	OptoHiT™	SyncFET™	VCX™
FAST®	OPTOLOGIC®	Sync-Lock™	VisualMax™
FastvCore™	OPTOPLANAR [®]	Sync-Lock ····	VoltagePlus™
FETBench™	OPTOPLANAR*	SYSTEM ®*	XS™
FlashWriter [®] *	®	GENERAL	
FPS™			

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or 2. system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness

6

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
		Rev